TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74AC151P,TC74AC151F,TC74AC151FN

8-Channel Multiplexer

The TC74AC151 is an advanced high speed CMOS 8-CHANNEL MULTIPLEXER fabricated with silicon gate and double-layer metal wiring $C^2MOS$ technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

One of eight date input signals (D0-D7) is selected by decoding of the three-bit address input (A, B, C). The selected data appears on two outputs: non-inverting (Y) and inverting (W).

The $\overline{\text{STROBE}}$ input provides two output conditions; a low level on the $\overline{\text{STROBE}}$ input transferrs the selected data to the outputs. A high level on the $\overline{\text{STROBE}}$ input sets the Y output low and the W output high without regard to the data or select input conditions.

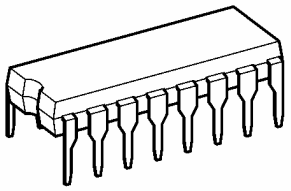
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

## Features

- High speed: $t_{pd}$ = 5.3 ns (typ.) at $V_{CC}$ = 5 V
- Low power dissipation: $I_{CC}$ = 8 μA (max) at Ta = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% $V_{CC}$ (min)
- Symmetrical output impedance: $|I_{OH}| = I_{OL}$ = 24 mA (min)
  Capability of driving 50 Ω transmission lines.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: $V_{CC}$ (opr) = 2 to 5.5 V
- Pin and function compatible with 74F151

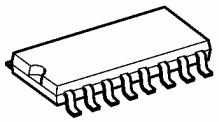
Note: xxxFN (JEDEC SOP) is not available in Japan.

TC74AC151P



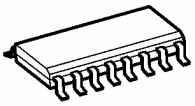
DIP16-P-300-2.54A

TC74AC151F



SOP16-P-300-1.27A

TC74AC151FN

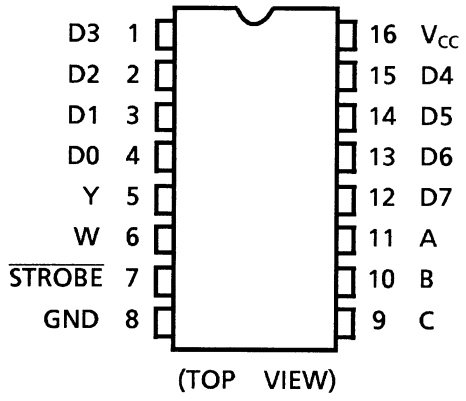


SOL16-P-150-1.27

Weight

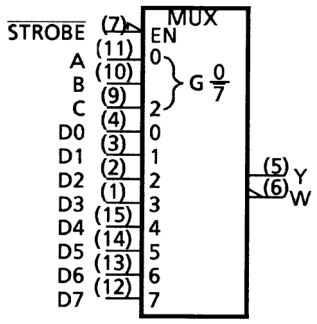
| | |
|---|---|
| DIP16-P-300-2.54A | : 1.00 g (typ.) |
| SOP16-P-300-1.27A | : 0.18 g (typ.) |
| SOL16-P-150-1.27 | : 0.13 g (typ.) |

## Pin Assignment




(TOP VIEW)

## IEC Logic Symbol

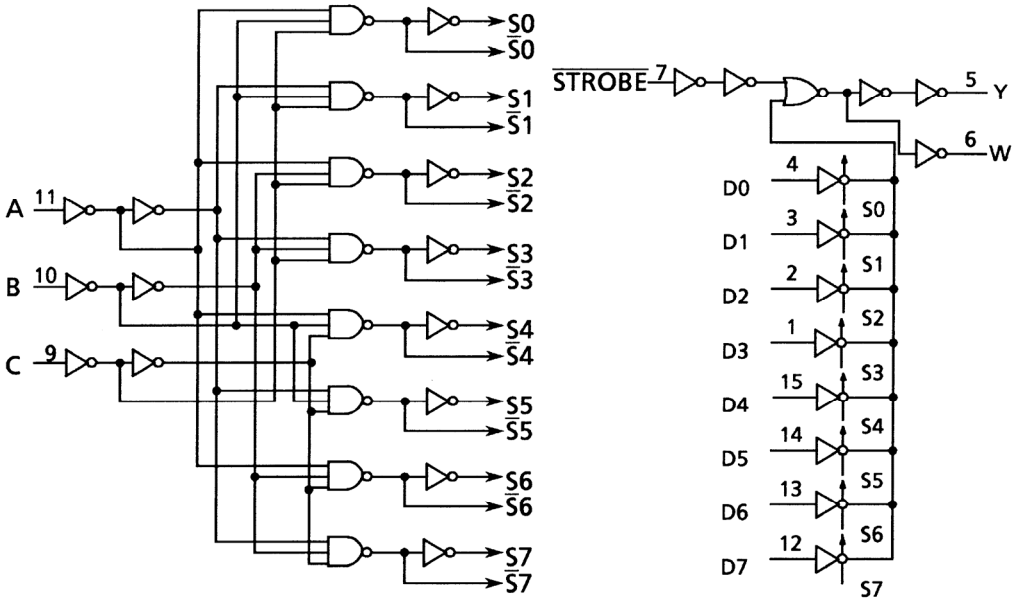



## Truth Table

| Inputs | | | | Outputs | |
|---|---|---|---|---|---|
| Select | | | $\overline{\text{STROBE}}$ | Y | W |
| C | B | A | | | |
| X | X | X | H | L | H |
| L | L | L | L | D0 | $\overline{D0}$ |
| L | L | H | L | D1 | $\overline{D1}$ |
| L | H | L | L | D2 | $\overline{D2}$ |
| L | H | H | L | D3 | $\overline{D3}$ |
| H | L | L | L | D4 | $\overline{D4}$ |
| H | L | H | L | D5 | $\overline{D5}$ |
| H | H | L | L | D6 | $\overline{D6}$ |
| H | H | H | L | D7 | $\overline{D7}$ |

X: Don’t care

## System Diagram



## Absolute Maximum Ratings (Note 1)

| Characteristics | Symbol | Rating | Unit |
|---|---|---|---|
| Supply voltage range | $V_{CC}$ | −0.5 to 7.0 | V |
| DC input voltage | $V_{IN}$ | −0.5 to $V_{CC}$ + 0.5 | V |
| DC output voltage | $V_{OUT}$ | −0.5 to $V_{CC}$ + 0.5 | V |
| Input diode current | $I_{IK}$ | ±20 | mA |
| Output diode current | $I_{OK}$ | ±50 | mA |
| DC output current | $I_{OUT}$ | ±50 | mA |
| DC $V_{CC}$/ground current | $I_{CC}$ | ±100 | mA |
| Power dissipation | $P_D$ | 500 (DIP) (Note 2)/180 (SOP) | mW |
| Storage temperature | $T_{stg}$ | −65 to 150 | °C |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = −40 to 65°C. From Ta = 65 to 85°C a derating factor of −10 mW/°C should be applied up to 300 mW.

## Operating Ranges (Note)

| Characteristics | Symbol | Rating | Unit |
|---|---|---|---|
| Supply voltage | $V_{CC}$ | 2.0 to 5.5 | V |
| Input voltage | $V_{IN}$ | 0 to $V_{CC}$ | V |
| Output voltage | $V_{OUT}$ | 0 to $V_{CC}$ | V |
| Operating temperature | $T_{opr}$ | −40 to 85 | °C |
| Input rise and fall time | dt/dV | 0 to 100 ($V_{CC}$ = 3.3 ± 0.3 V)<br>0 to 20 ($V_{CC}$ = 5 ± 0.5 V) | ns/V |

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

## Electrical Characteristics

### DC Characteristics

| Characteristics | Symbol | Test Condition | | $V_{CC}$ (V) | Ta = 25°C Min | Ta = 25°C Typ. | Ta = 25°C Max | Ta = −40 to 85°C Min | Ta = −40 to 85°C Max | Unit |
|---|---|---|---|---|---|---|---|---|---|---|
| High-level input voltage | $V_{IH}$ | — | | 2.0 | 1.50 | — | — | 1.50 | — | V |
| | | | | 3.0 | 2.10 | — | — | 2.10 | — | |
| | | | | 5.5 | 3.85 | — | — | 3.85 | — | |
| Low-level input voltage | $V_{IL}$ | — | | 2.0 | — | — | 0.50 | — | 0.50 | V |
| | | | | 3.0 | — | — | 0.90 | — | 0.90 | |
| | | | | 5.5 | — | — | 1.65 | — | 1.65 | |
| High-level output voltage | $V_{OH}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$ | $I_{OH}$ = −50 μA | 2.0 | 1.9 | 2.0 | — | 1.9 | — | V |
| | | | | 3.0 | 2.9 | 3.0 | — | 2.9 | — | |
| | | | | 4.5 | 4.4 | 4.5 | — | 4.4 | — | |
| | | | $I_{OH}$ = −4 mA | 3.0 | 2.58 | — | — | 2.48 | — | |
| | | | $I_{OH}$ = −24 mA | 4.5 | 3.94 | — | — | 3.80 | — | |
| | | | $I_{OH}$ = −75 mA (Note) | 5.5 | — | — | — | 3.85 | — | |
| Low-level output voltage | $V_{OL}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$ | $I_{OL}$ = 50 μA | 2.0 | — | 0.0 | 0.1 | — | 0.1 | V |
| | | | | 3.0 | — | 0.0 | 0.1 | — | 0.1 | |
| | | | | 4.5 | — | 0.0 | 0.1 | — | 0.1 | |
| | | | $I_{OL}$ = 12 mA | 3.0 | — | — | 0.36 | — | 0.44 | |
| | | | $I_{OL}$ = 24 mA | 4.5 | — | — | 0.36 | — | 0.44 | |
| | | | $I_{OL}$ = 75 mA (Note) | 5.5 | — | — | — | — | 1.65 | |
| Input leakage current | $I_{IN}$ | $V_{IN}$ = $V_{CC}$ or GND | | 5.5 | — | — | ±0.1 | — | ±1.0 | μA |
| Quiescent supply current | $I_{CC}$ | $V_{IN}$ = $V_{CC}$ or GND | | 5.5 | — | — | 8.0 | — | 80.0 | μA |

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

**AC Characteristics ($C_L$ = 50 pF, $R_L$ = 500 Ω, input: $t_r = t_f$ = 3 ns)**

| Characteristics | Symbol | Test Condition | | Ta = 25°C | | | Ta = −40 to 85°C | | Unit |
|---|---|---|---|---|---|---|---|---|---|
| | | | $V_{CC}$ (V) | Min | Typ. | Max | Min | Max | |
| Propagation delay time (D-Y, W) | $t_{pLH}$ | — | 3.3 ± 0.3 | — | 10.7 | 19.3 | 1.0 | 22.0 | ns |
| | $t_{pHL}$ | | 5.0 ± 0.5 | — | 6.6 | 10.5 | 1.0 | 12.0 | |
| Propagation delay time (A, B, C-Y, W) | $t_{pLH}$ | — | 3.3 ± 0.3 | — | 13.3 | 23.7 | 1.0 | 27.0 | ns |
| | $t_{pHL}$ | | 5.0 ± 0.5 | — | 8.2 | 13.0 | 1.0 | 14.8 | |
| Propagation delay time ($\overline{ST}$ -Y, W) | $t_{pLH}$ | — | 3.3 ± 0.3 | — | 8.6 | 15.3 | 1.0 | 18.0 | ns |
| | $t_{pHL}$ | | 5.0 ± 0.5 | — | 5.6 | 9.6 | 1.0 | 11.0 | |
| Input capacitance | $C_{IN}$ | — | | — | 5 | 10 | — | 10 | pF |
| Power dissipation capacitance | $C_{PD}$ (Note) | — | | — | 68 | — | — | — | pF |

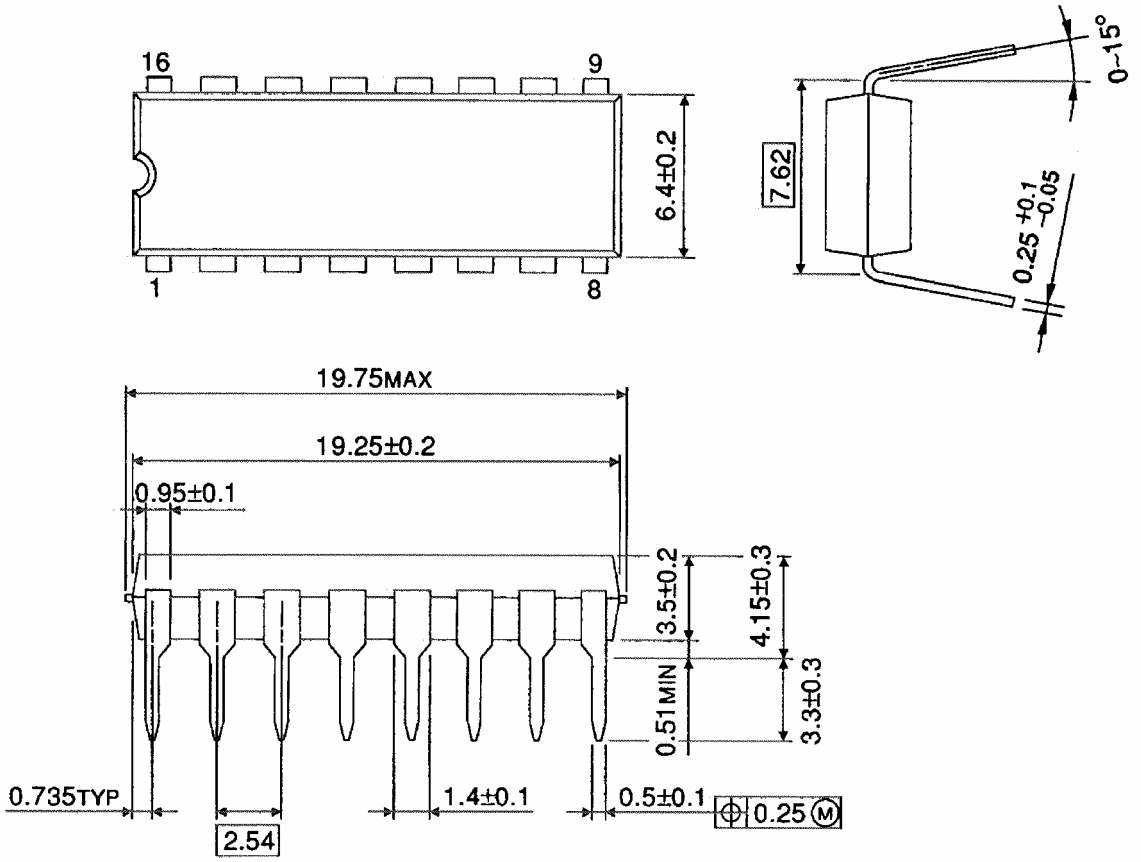
Note: $C_{PD}$ is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}\ (opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

## Package Dimensions

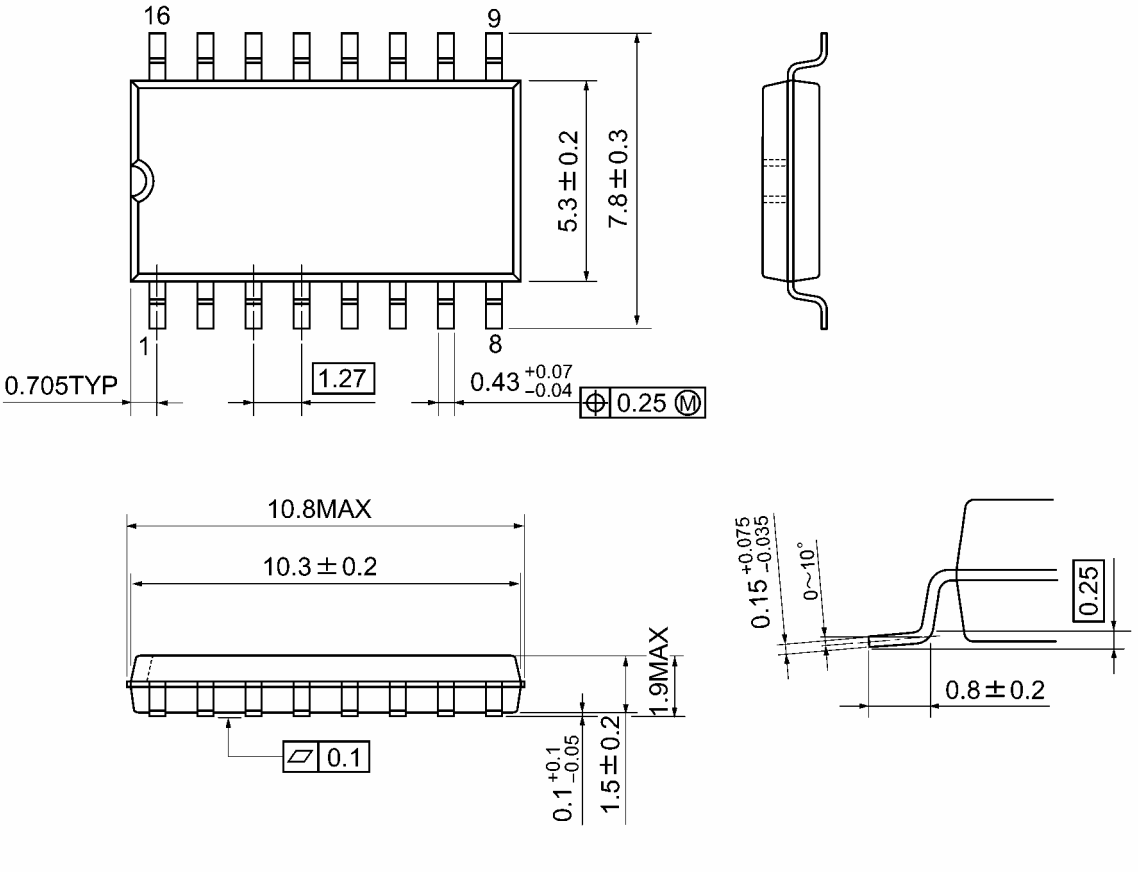
DIP16-P-300-2.54A Unit : mm




Weight: 1.00 g (typ.)

## Package Dimensions

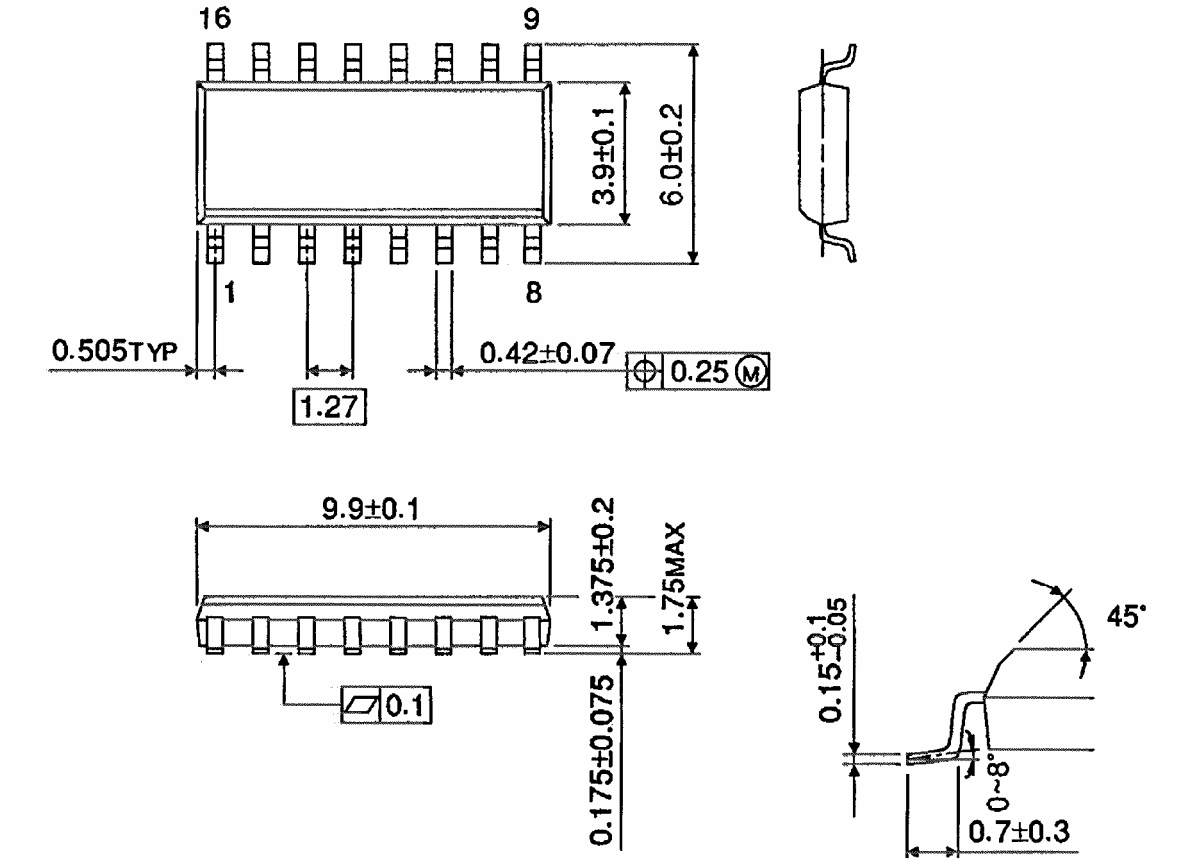
SOP16-P-300-1.27A Unit: mm




Weight: 0.18 g (typ.)

**Package Dimensions (Note)**

SOL16-P-150-1.27 Unit : mm




Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

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20070701-EN GENERAL

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